9097250 TOSHIBA (DISCRETE/OPTO) 67C 09297 D 7-01-09

Unit in mm

1S1553~1S1555 Silicon Epitaxial Planar Type

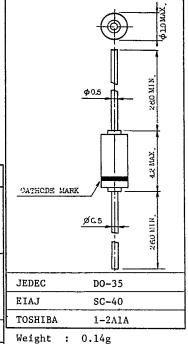
GENERAL PURPOSE APPLICATION FOR DETECTOR AND RECTIFIER.

FEATURES:

- . Low Forward Voltage : VF=1.0V (Typ.)
- . Small Total Capacitance : CT=1.3pF (Typ.)

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
: Maximum (Peak) Reverse Voltage	181553		70	V .	
	181554	v _{RM}	55		
	181555		35		
Reverse Voltage	181553		60	v	
	181554	v_R	50		
	181555		30		
Maximum (Peak) Forward Current		IFM	300	mA	
Average Forward Current		IO	100	mA	
Surge Current (1 sec)		IFSM	1	A	
Power Dissipation		P	300	mW	
Junction Temperature		Tj .	150	°C	
Storage Temperat	Tstg	-65~150	°C		



Marking

181553 1S1554

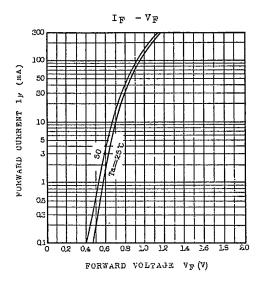
1S1555

FIFCTRICAL CHARACTERISTICS (Ta=25°C)

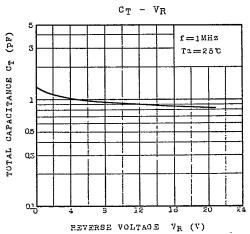
ELECTRICAL CHARACTERISTICS (Ta=25 C)			ੋਰ -				
CARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage		v _F	I _F =100mA	-	1.0	1.4	V
Reverse Current	181553	I _R	V _R =60V		-	0.5	μΑ
	181554		V _R =50V	-			
	181555		V _R =30V				
Total Capacitano	e	CT	V _R =0 f=1MHz	_	1.3	3.5	pF

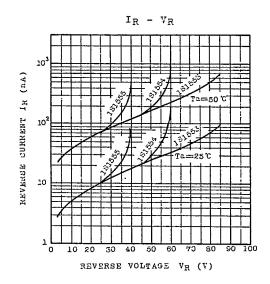
TOSHIBA CORPORATION

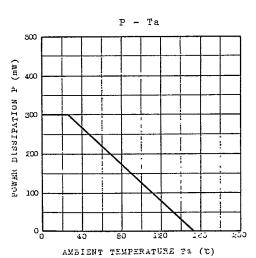
-1S1553~1S1555



9097250 TOSHIBA (DISCRETE/OPTO)







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